



Introduction

Jeppe Hinrichs, background in electrical engineering

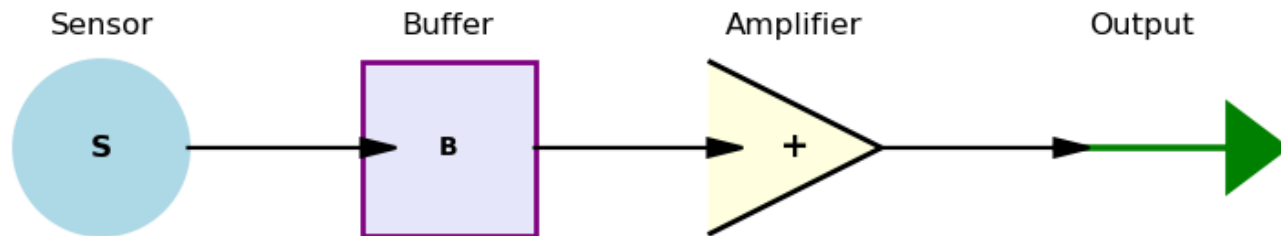
Currently in DkCCC/NL as a process specialist

Prior experience as a researcher in biomedical microsystems laboratory

My agenda: Integrating sensors with microelectronics

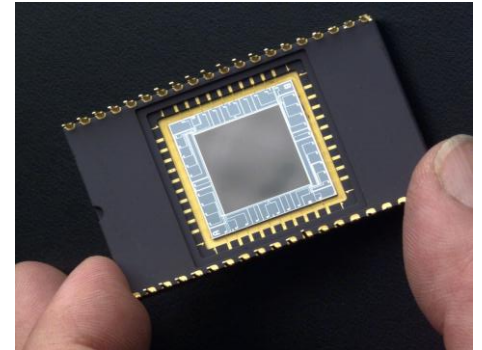
Transistor enhanced sensors from DTU NL

- Current: MOS capacitor fabrication
- Goal: Fabricate FET structure and validate with characterization
- Target: High-performance, flexible, multi-functional sensors



- Previous sensors from NL include:

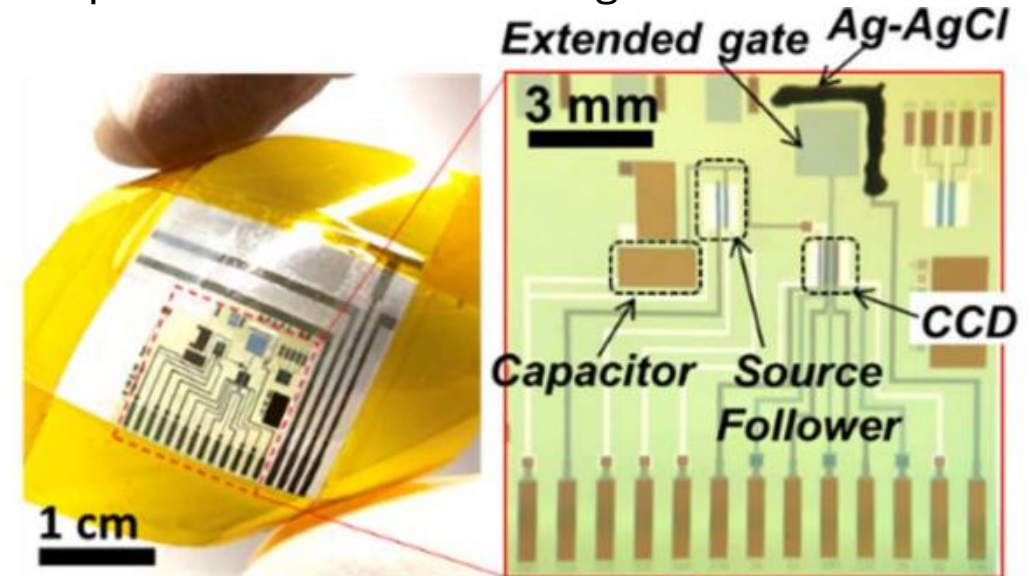
- Temperature
- Humidity
- Pressure
- Light
- Sound
- Ultrasound transducer
- Accelerometer
- Chemical/Nose
- Magnetic field



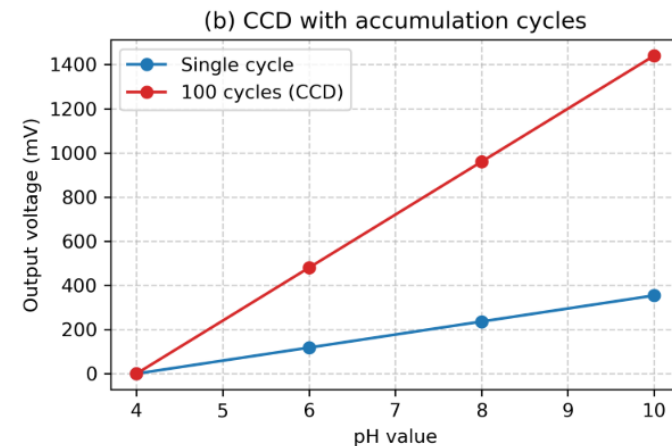
Example of Benefits

Example of a pH sensor with CCD integration to beat Nernst limit

- Broad benefits of transistor integration with sensors
 - Signal amplification – Boost weak sensor signals before degradation by interconnects
 - Higher sensitivity – CCD/FET architectures can use electronic control for increased resolution
 - Miniaturization – reduced need for external electronics
 - Multi-parameter sensing – Allows integration of different sensing modalities



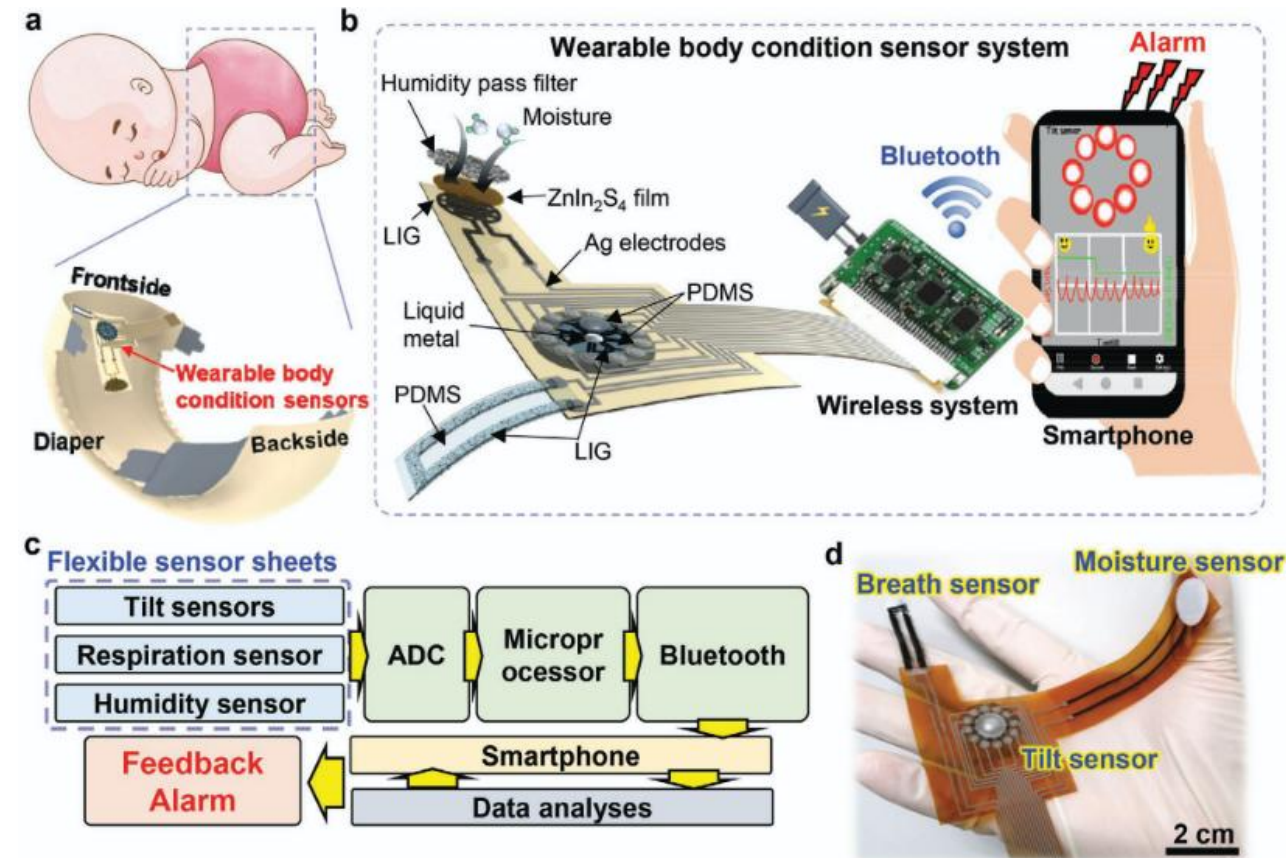
(10.1109/TRANSDUCERS.2019.8808504)



Future potential

- Expand to chemical, biological, and physical sensing
- Physical modalities
 - Wearable
 - Implantable (if biocompatible)
 - Environmental monitoring
- Compact, flexible, multi-sensor platforms

Example of a multisensor wearable to prevent SIDS:



(10.1002/adma.202008701)

Next steps and anticipated timing

- Phase 1: Foundation (MOSCAP) – 2025 Q4
 - Objective: Master basic CMOS process (oxidation, LPCVD, litho, metal.)
 - Deliverable: Validation of 6" process flow, characterization of LF/HF C-V and I-V.
 - Coordination: Self-contained process, mentoring with fabrication support
- Phase 2: Transistors – 2026 Q1
 - Objective: Transition to MOSFETs on rigid substrate, planar test structures
 - Deliverable: Id-Vg, Id-Vd curves, transistor parameters, mobility
 - Coordination: Coordination with characterization groups

- Phase 3: Integration – TBD
 - Objective: Develop FET process with sensor design, integration of FET/CCD topologies
 - Deliverable: Prototype transistor integration
 - Target application:
 - Chemical/bio/imaging sensors
 - Others (?)

To Be Determined